Supplementary figures



Supplementary Figure 1 | Evolution of the electron doping level upon K evaporation. The grey line is a guide for the eye to show how the system evolves towards saturation upon consecutive K evaporation. Previous STM studies reported that the K atoms stay on the surface of the film [1, 2, 3]. Parts (could be all with very low coverage) of them are ionized, as supported by the observation of the K atom clusters with increasing coverage (>0.2ML) in the STM images. Unfortunately, we are not equipped with a low-temperature STM with atomic resolution. However, our ARPES (a sophisticated version of photoemission compared to XPS) data clearly show a chemical potential shift, thus indicating electron-doping in our experiment. The extra electrons can only come from the ionization of K.



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16 Supplementary Figure 2 | Evolution of the energy distribution curves (EDCs) upon K 17 deposition. a-b, Potassium coating evolution of the EDC plots at 14 K near Γ and M along 18 the direction shown in the inset of Fig. 1 e. c, EDC plots along the same cut as in a, but 19 recorded at 70 K. The EDCs are divided by the Fermi-Dirac distribution function convoluted 20 by the resolution function to visualize the states above $E_{\rm F}$.



23 Supplementary Figure 3 | LDA band structures. a, Calculated electronic band structure of 24 pristine monolayer FeSe. b, Calculated electronic band structure of FeSe topped by one layer of K, with one K atom per unit cell of FeSe. The gap between the d_{xy}/p_z band and the d_{xz}/d_{yz} 25 band at Γ decreases from 270 to 180 meV with K deposition, and there is no band related to 26 K nearby. In both cases, the lattice constant is 3.8 Å and the internal atomic positions are 27 28 fully relaxed. c, Atomic positions of the pristine and K topped monolayer FeSe. In the former, 29 the bond length of Fe-Se is 2.366. In the latter, the bond lengths of Fe-Se(top) and Fe-30 Se(bottom) are 2.36866 and 2.36250, respectively.



33 Supplementary Figure 4 | Superconducting gap of potassium-coated 1UC FeSe/STO 34 with the doping level of x = 0.214. a, Temperature evolution of the symmetrized EDCs at 35 the k_F point of the electron FS around M. The red curves correspond to fit of the data. b, 36 Superconducting gap sizes as a function of temperature obtained from the fits shown in a. 37 Error bars are estimated from the standard deviation of the fitting.



Supplementary Figure 5 | Comparison of the spectra at different temperatures for each
sample. a, ARPES intensity plots near the M point recorded at the low and high temperature
for the pristine 1UC FeSe/STO. The spectra are divided by the Fermi-Dirac function in order
to access partly the unoccupied states. b-d, Same as a but for the potassium-coated film with
the electron-doping level indicated above the panels, respectively.





Supplementary Figure 6 | Temperature evolution of the EDCs. a-c, Temperature evolution of the EDCs at the $k_{\rm F}$ point of the electron FS around M for pristine and potassiumcoated 1UC FeSe/STO. The electron doping is indicated above the panels.



53 Supplementary Figure 7 | Refection high-energy electron diffraction (RHEED) image.

54 RHEED image of the pristine monolayer film of FeSe/STO after annealing at 350 °C for 20h.

56 Supplementary References

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